

# 1N4148W

## SWITCHING DIODE

### FEATURES

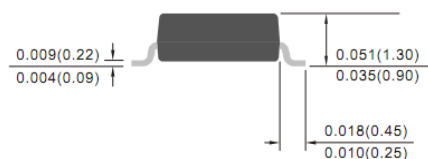
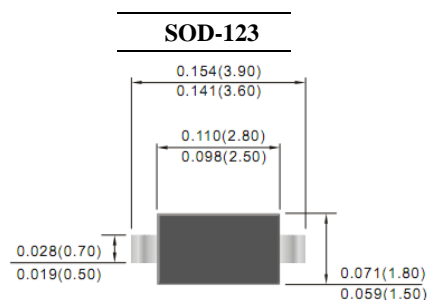
- For surface mounted applications
- Glass Passivated Chip Junction
- Fast reverse recovery time
- Ideal for automated placement
- Lead free in comply with EU RoHS 2011/65/EU directives

### MECHANICAL DATA

- Case: SOD-123
- Terminals: Solderable per MIL-STD-750, Method 2026

### Marking

Type number	Marking code
1N4148W	T4



**Dimensions in inches and (millimeters)**

### Absolute Maximum Ratings at 25 °C

Parameter	Symbols	1N4148W	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	V
Maximum RMS voltage	$V_{RMS}$	75	V
Continuous Forward Current	$I_F$	300	mA
Non-reptitive Peak Forward Surge Current at 1ms	$I_{FSM}$	4	A
Total Power Dissipation	$P_{tot}$	400	mW
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150	°C

### Characteristics at $T_a = 25\text{ °C}$

Parameter	Symbols	1N4148W	Units
Reverse Breakdown Voltage at $I_R = 1\mu\text{A}$	$V_{(BR)R}$	75	V
Maximum Forward Voltage at 1 mA at 10 mA at 50 mA at 150 mA	$V_F$	0.715 0.855 1.00 1.25	V
Peak Reverse Current at $V_R = 20\text{V}$ $T_j = 25\text{°C}$ at $V_R = 75\text{V}$ $T_j = 25\text{°C}$ at $V_R = 25\text{V}$ $T_j = 150\text{°C}$ at $V_R = 75\text{V}$ $T_j = 150\text{°C}$	$I_R$	0.025 1 30 50	$\mu\text{A}$
Typical Junction Capacitance	$C_j$	5	pF
Maximum Reverse Recovery Time	$t_{rr}$ Typical	8	ns

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Fig.1 Forward Current Derating Curve

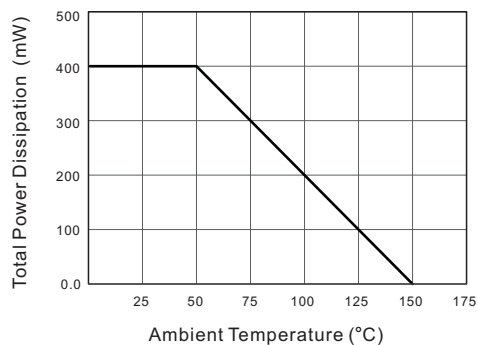


Fig.2 Typical Reverse Characteristics

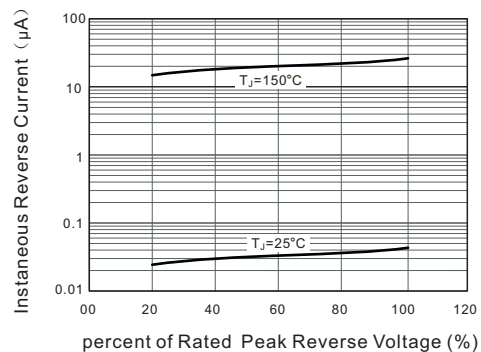


Fig.3 Typical Instantaneous Forward Characteristics

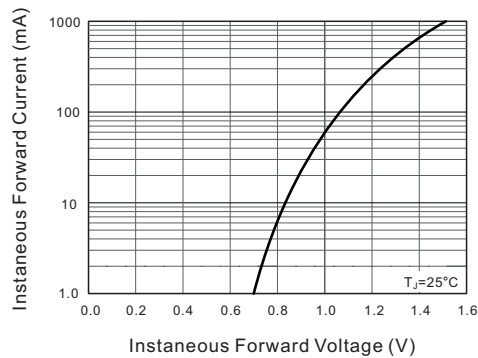


Fig.4 Typical Junction Capacitance

